PTO/SB/21 (modified) Approved for use through xx/xx/xx, OMB 0651-0031 Patent and Trademark Office: U.S. DEPARTMENT OF COMMERCE U.S. Department of Commerce Application Number 10/087,408 Rev. 10/95 Patent and Trademark Office Filing Date March 1, 2002 TRANSMITTAL FORM First Named Inventor Xiaodong Huang (to be used for all correspondence during pendency of Group Art Unit Number 2828 filed application) **Examiner Name** James W. Davie Total Number of Pages in This Submission Attorney Docket Number 22920-06460 **ENCLOSURES** (check all that apply) Fee Transmittal Form (in duplicate) Issue Fee Transmittal Check Enclosed Letter to Chief Draftsperson Return Receipt Postcard Formal Drawing(s): Response to Notice to File Missing Parts [] Sheet(s) of Figure(s) [] Assignment & Recordation Cover Sheet Appeal Communication to Board of Appeals and Interferences Declaration Power of Attorney Appeal Communication to Group (Appeal Notice, Brief, Reply Brief) **Application Data Sheet** Information Disclosure Statement & PTO/SB/08A Certified Copy of Priority Document(s) Copies of IDS Cited References After Allowance Communication to Group Request for Corrected Filing Receipt Request for Correction of Recorded Assignment Amendment/Response: [] Page(s). After Final Status Request

| A SIGNATURE OF ATTORNEY OR AGENT | | | | |
|----------------------------------|----------------------------------|--------|---------|--------|
| Signature: | whelaelul ? | | | |
| Attorney/Reg. No.: | Michael W. Farn, Reg. No. 41,015 | Dated: | June // | , 2003 |

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REMARKS: * Does not include pages in reference(s).

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

ICANT(S):

Xiaodong Huang, Andreas Stintz, Kevin Malloy, Guangtian Liu,

Luke Lester and Julian Cheng

APPLICATION NO.:

10/087,408

FILING DATE:

March 1, 2002

TITLE:

Quantum Dot Vertical Cavity Surface Emitting Laser

EXAMINER:

James W. Davie

GROUP ART UNIT:

2828

ATTY. DKT. NO.:

22920-06460

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THIRD INFORMATION DISCLOSURE STATEMENT Under 37 CFR §§ 1.56 and 1.97-98

SIR:

Pursuant to the provisions of 37 CFR §§ 1.56 and 1.97-98, enclosed herewith is modified form PTO/SB/08A listing references for consideration by the Examiner. Enclosed is a copy of each listed reference that may be material to the examination of this application, and for which there may be a duty to disclose.

The filing of this Information Disclosure Statement shall not be construed as a representation regarding the completeness of the list of references, or that inclusion of a reference in this list is an admission that it is prior art or is pertinent to this application, or that a search has been made, or as an admission that the information listed is, or may be considered to be, material to patentability, or that no other material information exists, and shall not be construed as an admission against interest in any manner.

This Information Disclosure Statement is being filed:

within three months of the filing date of the application, or date of entry into the national stage of an international application, or before the mailing date of a first office action on the merits, whichever event last occurred;

| | neiote tile il | nailing of a first official action after the filing of a request for |
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| | continued e | xamination (RCE) under 37 CFR § 1.114; |
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| | or entry of t | he national stage in an international application, or after the |
| | mailing date | e of the first official action on the merits, whichever event last |
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| | final action | under 37 CFR §1.113; or (2) an action that otherwise closes |
| - | | in the application, and: |
| | ☐ atta | ched hereto is the fee set forth under 37 CFR §1.17(p) for |
| | | mission of this Information Disclosure Statement under 37 |
| | | R.§ 1.97(c); OR |
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| | | This a | | on relies, under 35 U.S.C. § 120, on the earlier filing date of prior |
| | | applic | ation No | o.[APPLICATION NUMBER], filed on [FILING DATE], and the |
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| | Consid | leration | of the li | sted references and favorable action are solicited. |
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| | | | | Respectfully submitted, XIAODONG HUANG et al. |
| | | | | AMODONO HOANG et al. |
| Dotad. | т | 10 | | 11 0 017 |
| Dated: | June | 11 | , 2003 | By: Mickae W |
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Substitute for form 1449A/PTO Complete if Known Application No. 10/087,408 INFORMATION DISCLOSURE Filing Date March 1, 2002 STATEMENT BY APPLICANT **First Named Inventor** Xiaodong Huang Art Unit

2828 **Examiner Name** James W. Davie Sheet of 2 Attorney Docket Number 22920-06460

| · | | | U.S. PAT | ENT DOCUMENTS |
|-----------------------|--------------|--|--------------------|--|
| | | Document No. | | |
| Examiner Initials* | Cite No.1 | Number – Kind Code ² (if known) | Date MM-DD-YYYY | Name of Patentee or Applicant of Cited Document |
| | 1 | US-5,781,575 A | 07-14-1998 | Nilsson |
| | 2 | US-5,930,278 A | 07-27-1999 | Menigaux |

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| | | Foreign Patent Document | | | |
| Examiner Initials* | Cite No.1 | Country Code ³ – Number ⁴ Kind Code ⁵ (if known) | Publication Date MM-DD-YYYY | Name of Patentee or Applicant of Cited Document | T ⁶ |
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| | | OTHER REFERENCES – NON-PATENT LITERATURE DOCUMENTS | |
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| Examiner Initials* | Cite No. ¹ | Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published | T ⁶ |
| | 3 | Bloch, J. et al., "Room-temperature 1.3 μm emission from InAs quantum dots grown by metal organic chemical vapor deposition," <i>Applied Physics Letters</i> , American Institute of Physics, New York, U.S., Vol. 75, No. 15, October 11, 1999, pages 2199-2201. | |
| · · · · · · · · · · · · · · · · · · · | 4 | Evans, P.W. et al., "Edge-emitting quantum well heterostructure laser diodes with auxiliary native-oxide vertical cavity confinement," <i>Applied Physics Letters</i> , American Institute of Physics, New York, U.S., Vol. 67, No. 21, November 20, 1995, pages 3168-3170. | |
| | 5 | Garcia, J.M. et al., "Electronic states tuning of InAs self-assembled quantum dots," <i>Applied Physics Letters</i> , American Institute of Physics, New York, U.S., Vol. 72, No. 24, June 15, 1998, pages 3172-3174. | |
| | 6 | Kim, Jin K. et al., "Lateral Carrier Confinement in Miniature Lasers Using Quantum Dots," <i>IEEE Journal of Selected Topics in Quantum Electronics</i> , IEEE Service Center, U.S., Vol. 6, No. 3, May/June 2000, pages 504-510. | |
| | 7 | Ledentsov N.N. et al., "Interconnection between gain spectrum and cavity mode in a quantum-dot vertical-cavity laser," <i>Semiconductor Science and Technology</i> , Institute of Physics, London, G.B., Vol. 14, No. 1, 1999, pages 99-102. | |

| Examiner Signature | | Date Considered | · | |
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Sheet

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| Application No. | 10/087,408 | | |
| Filing Date | March 1, 2002 | | |
| First Named Inventor | Xiaodong Huang | • | |
| Art Unit | 2828 | | |
| Examiner Name | James W. Davie | | |
| Attorney Docket Number | 22920-06460 | | |

| | | OTHER REFERENCES – NON-PATENT LITERATURE DOCUMENTS | |
|-----------------------|--------------------------|--|----------------|
| Examiner Initials* | Cite No. ¹ | Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published | T ⁶ |
| | 8 | Park, Gyoungwon et al., "Temperature Dependence of Gain Saturation in Multilevel Quantum Dot Lasers," <i>IEEE Journal of Quantum Electronics</i> , IEEE Inc., New York, U.S., Vol. 36, No. 9, September 2000, pages 1065-1071. | |
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| | 11 | Shchekin, Oleg B. et al., "Low-Threshold Continuous-Wave Two-Stack Quantum-Dot Laser with Reduced Temperature Sensitivity," <i>IEEE Photonics Technology Letters</i> , IEEE Inc., New York, U.S., Vol. 12, No. 9, September 2000, pages 1120-1122. | - |
| | 12 | Ustinov, V.M. et al., "High output power CW operation of a quantum dot laser," <i>Compound Semiconductors 1999</i> , Proceedings of the 26 th International Symposium on Compound Semiconductors, Berlin, Germany, August 22-26, 1999, Institute of Physics Conference Series, IOP Publishing Ltd., London, G.B., No. 166, pages 277-280. | |
| | 13 | PCT International Search Report, International Application No. PCT/US01/31256, May 27, 2003, 7 pages. | |
| | 14 | PCT International Search Report, International Application No. PCT/US02/06221, May 27, 2003, 4 pages. | |

| Examiner Signature | Date Considered | |
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